



MEASUREMENT COMPARISONS BETWEEN OPTICAL AND MECHANICAL EDGES FOR A SILICON MICROMACHINED DIMENSIONAL CALIBRATION STANDARD

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- 1. Sandia National Laboratories**
- 2. Micro Encoder Inc**
- 3. Mitutoyo America Corporation**



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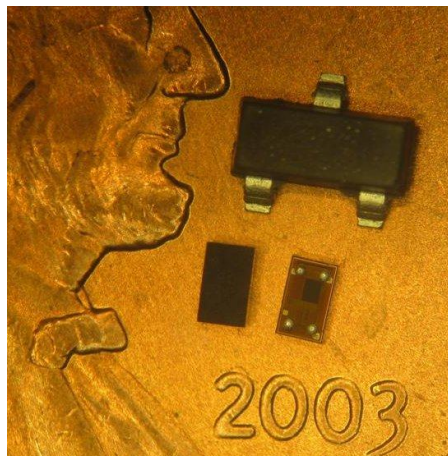
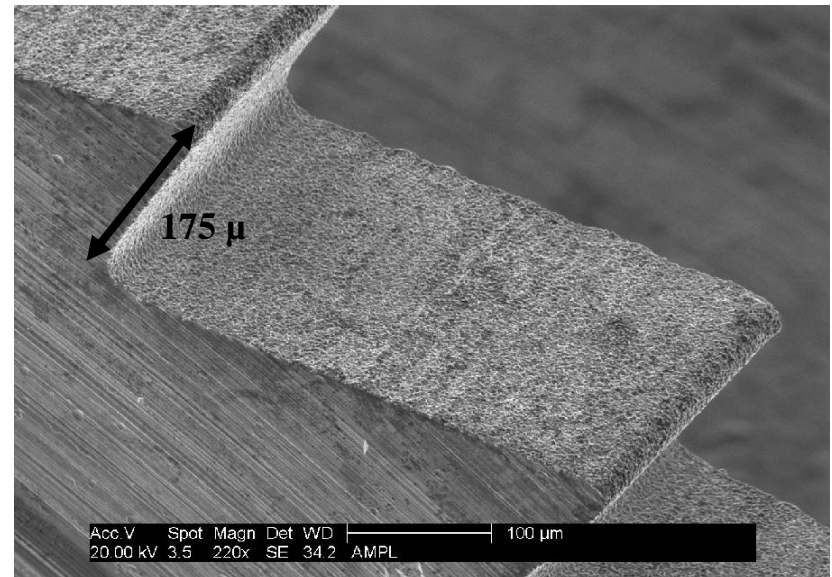
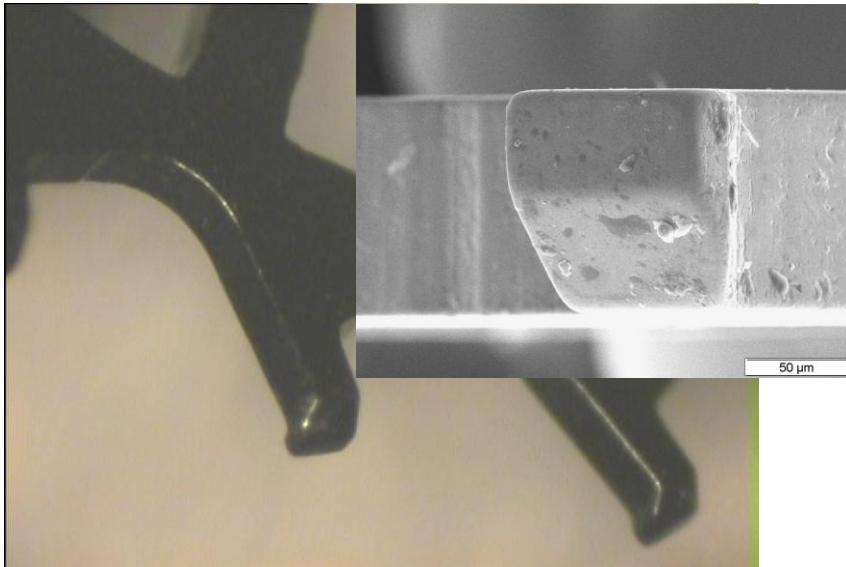




Outline of Presentation

- **Motivation for work: Inspection of mm-scale parts with μm to sub- μm measurement uncertainty**
- **Development of bulk-micromachined silicon calibration standard, with a common mechanical (touch probe) and optical (vision) edge**
- **Experimental Results**
- **Conclusions**

Examples of Mesoscale Components





Typical Capabilities for Existing Systems

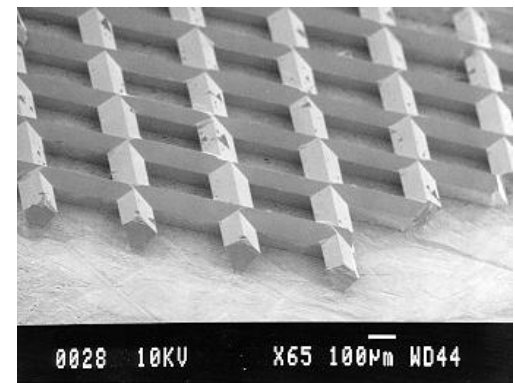
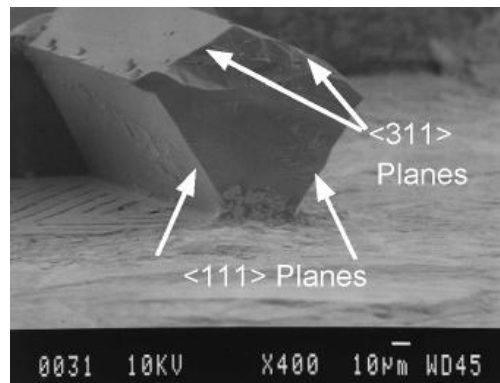
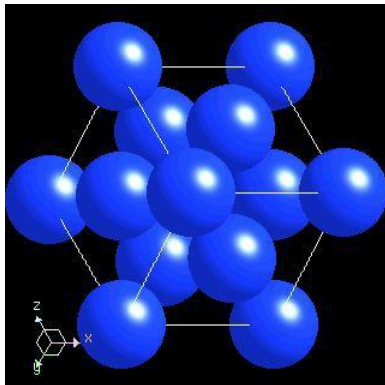
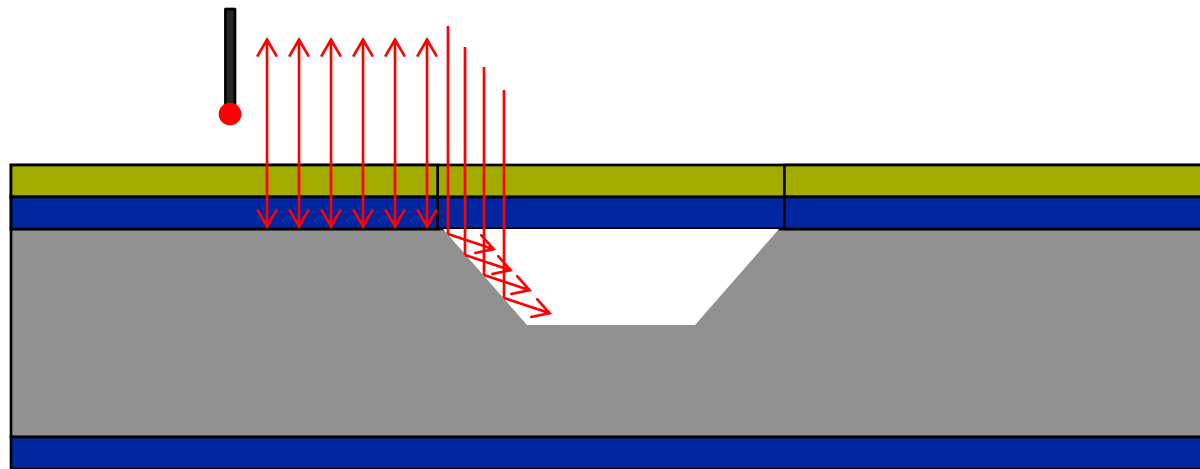
- Vision system repeatability typically order of $0.1\mu\text{m}$ (using averaging)
- Typical measurement uncertainties from various manufacturers and models (vision):
 - $1.5 + 4L/1000 \mu\text{m}$
 - $0.5 + 2L/1000 \mu\text{m}$
 - $1.0 + 2L/1000 \mu\text{m}$
- Typical measurement uncertainties for Micro CMM's:
 - $0.3 + L/1000 \mu\text{m}$
 - $0.25 + 1.5L/1000 \mu\text{m}$
- Hybrid, or multi-sensor systems with both stylus & non-contact (vision) sensor



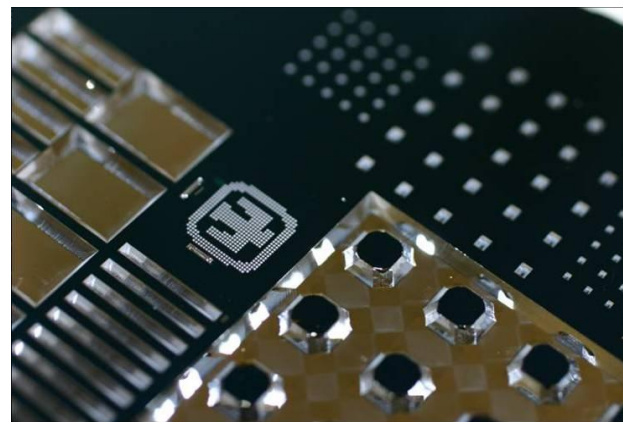
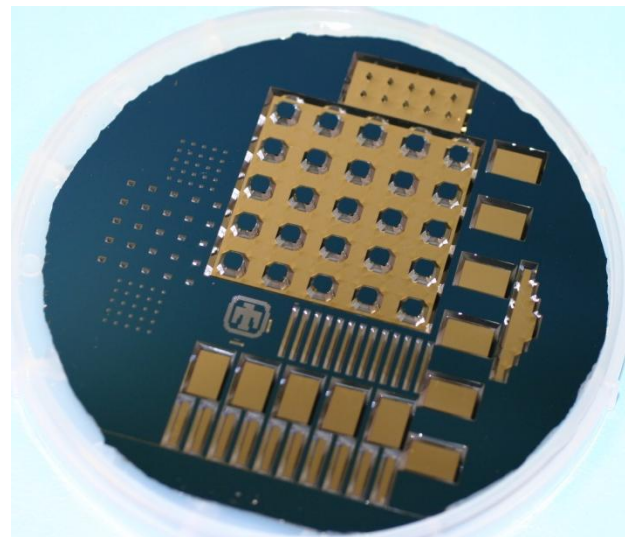
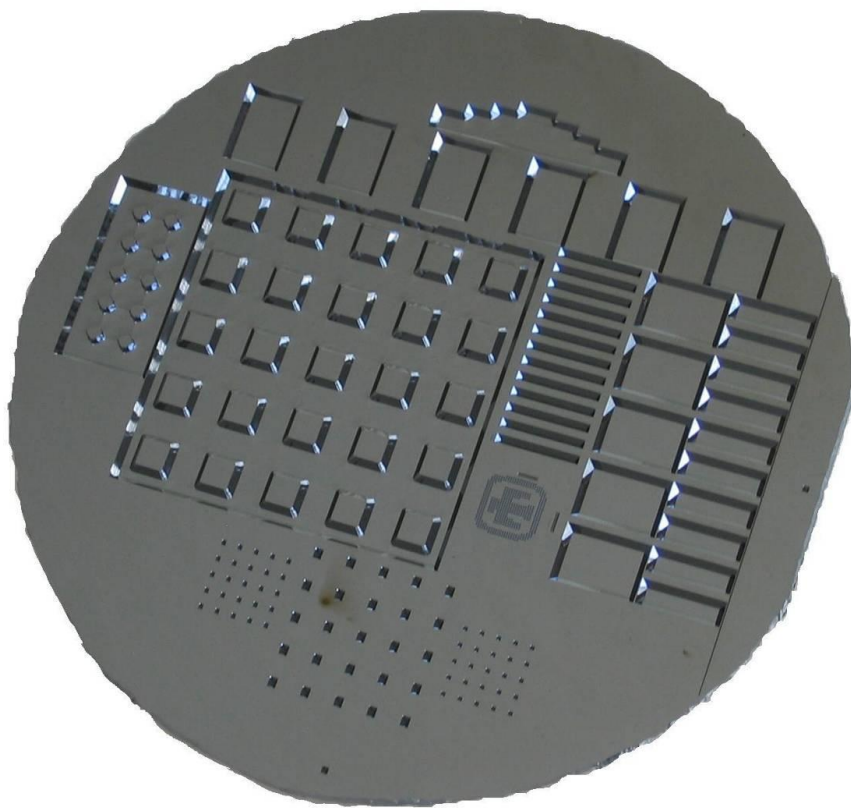
How Do We Improve Calibration?

- The accuracy of vision systems is typically limited by calibration artifact, not resolution:
 - Calibration artifact accuracy $\sim 1\mu\text{m}$
 - System repeatability $\sim 0.1\mu\text{m}$
- Can we design a better calibration tool?
- Can we make a calibration artifact that satisfies the needs for vision systems, micro CMM's, and multisensor systems?

Si Bulk Micromachining

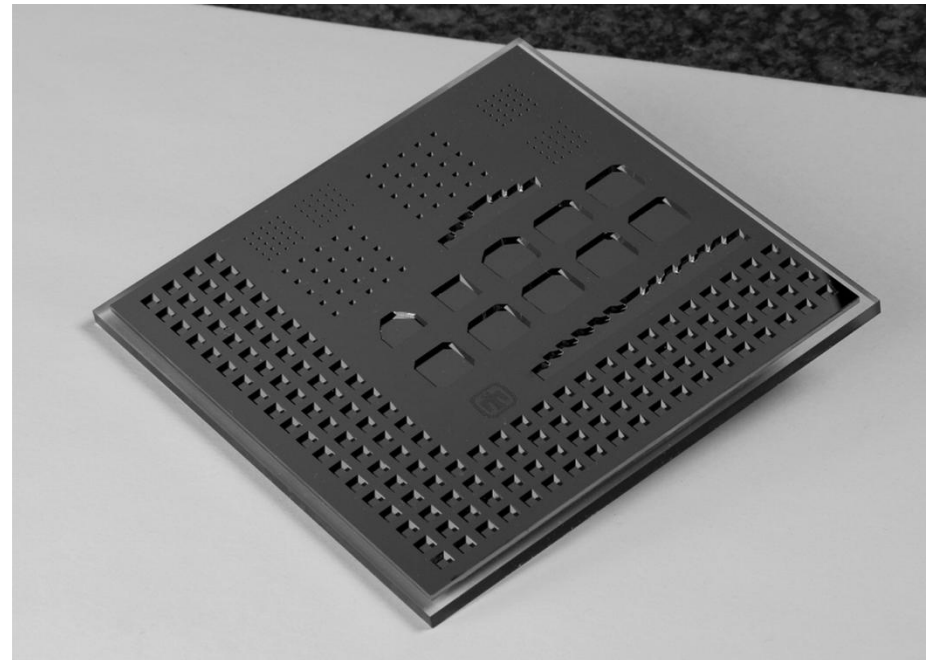
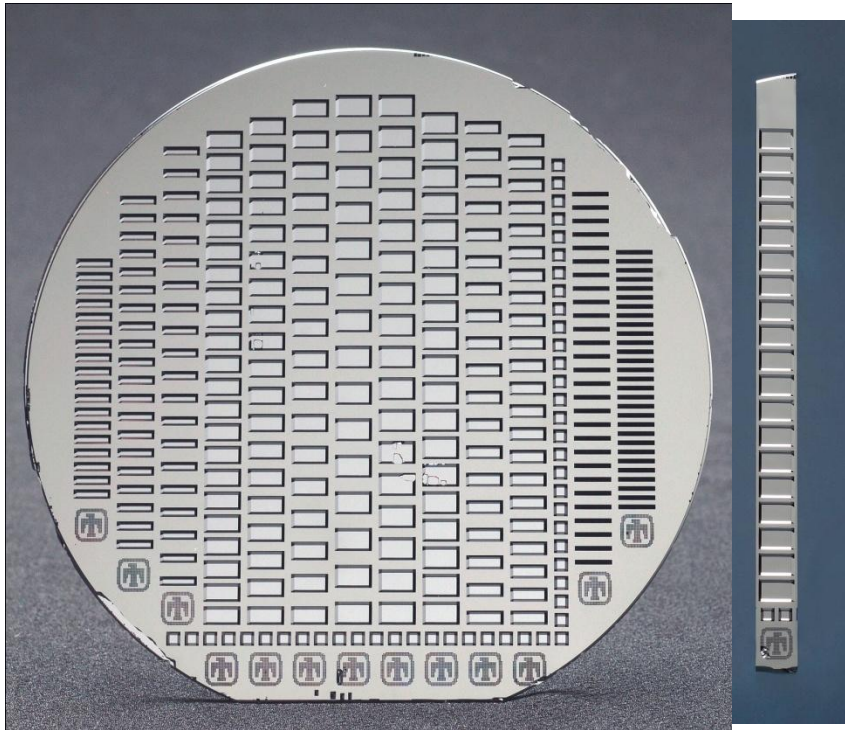


Initial Test Structures

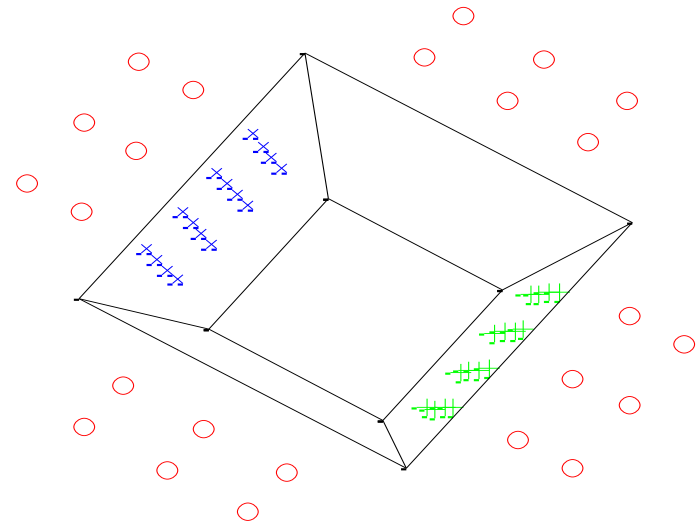
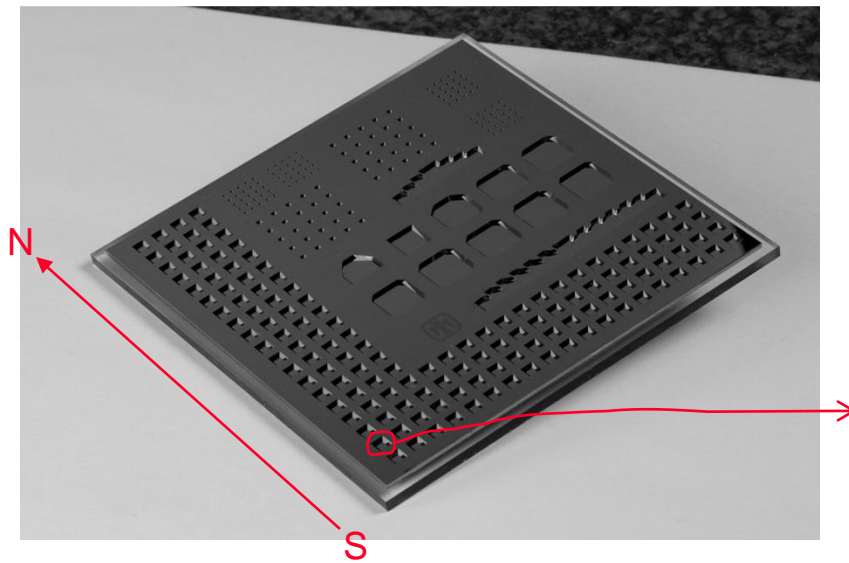


Second Design Iteration

- Process improvement studies (etch optimization; mask alignment improvements)
- Two designs, based on user feedback (using 150 mm wafers)

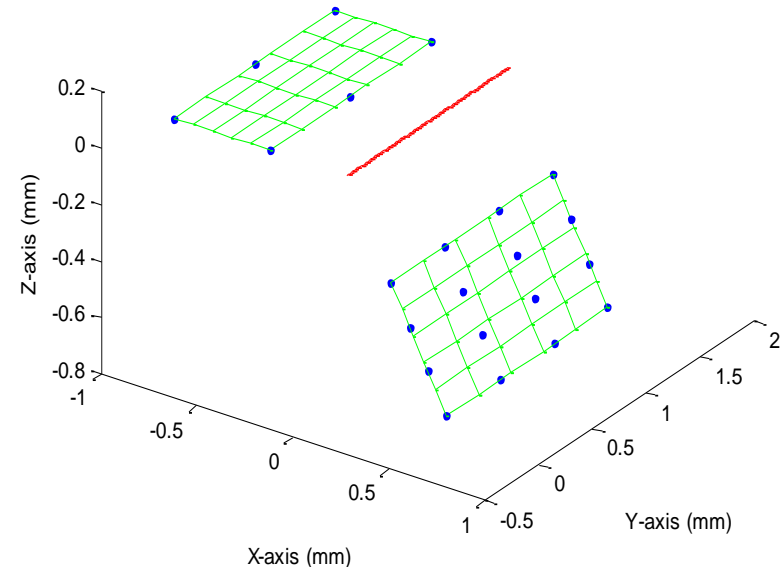


Probing on CMM

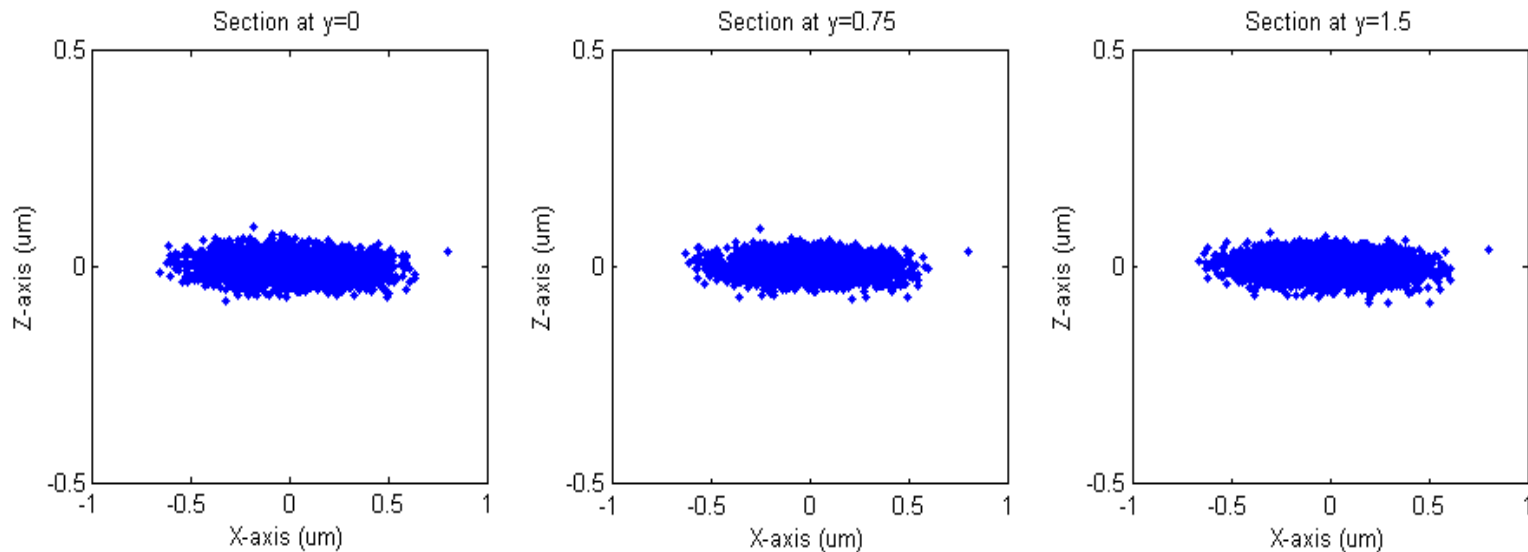


Surface Roughness of Silicon Artifact

- Process optimization in alignment and etch parameters performed, but sidewalls are still not as smooth as top surfaces.
 - Top surfaces have combined form/roughness deviations ± 100 nm over 5 mm span
 - Etched sidewalls have combined form/roughness deviations ± 600 nm over a 5 mm span
- Form and roughness deviations may lead to greater uncertainty in the location of the plane or the projected intersection line (edge)
- Form and roughness deviations have minor effects on the location of the midpoint between two edges!



Monte Carlo Simulations for Effects of Roughness



- Plots from 5000 simulated data sets, using statistics from actual CMM data \rightarrow $0.4\text{ }\mu\text{m}$ uncertainty at $k=2$ for location of a single edge
- Note that roughness should not have an effect on the distance of the pitch between adjacent cavities

Measurement Comparisons

- Leitz PMM-C-Infinity 12.10.6 at Sandia National Laboratories
- OGP Smartscope Apex at Sandia National Laboratories
- Mitutoyo QV Ultra at Micro Encoder Inc with a 25 X objective
- 2 Mitutoyo M-Nanocoord; one with UMAP and vision probing; other with long range ultralow scanning probe (LNP)
- Mitutoyo Formtracer CS-3100 at Mitutoyo America Corp, Aurora, IL



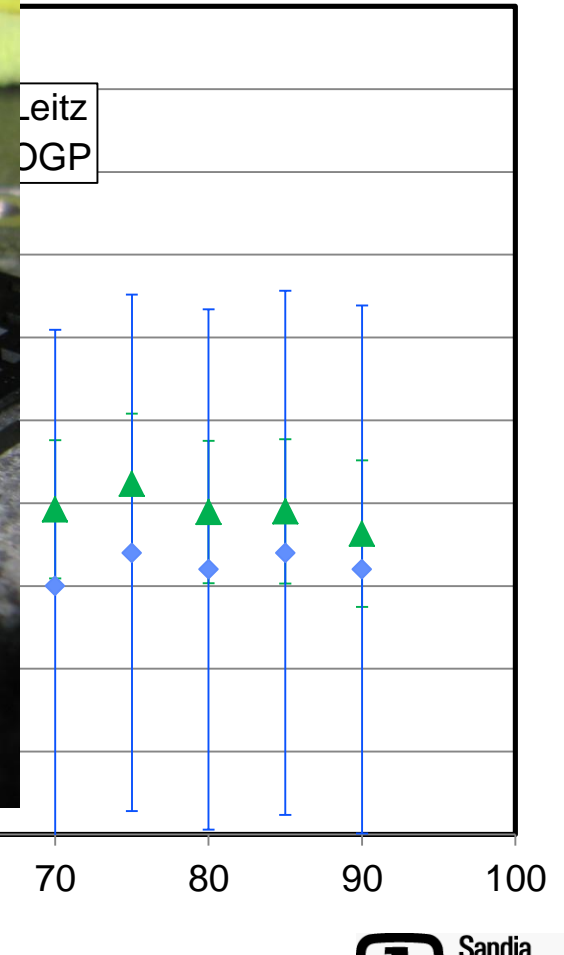
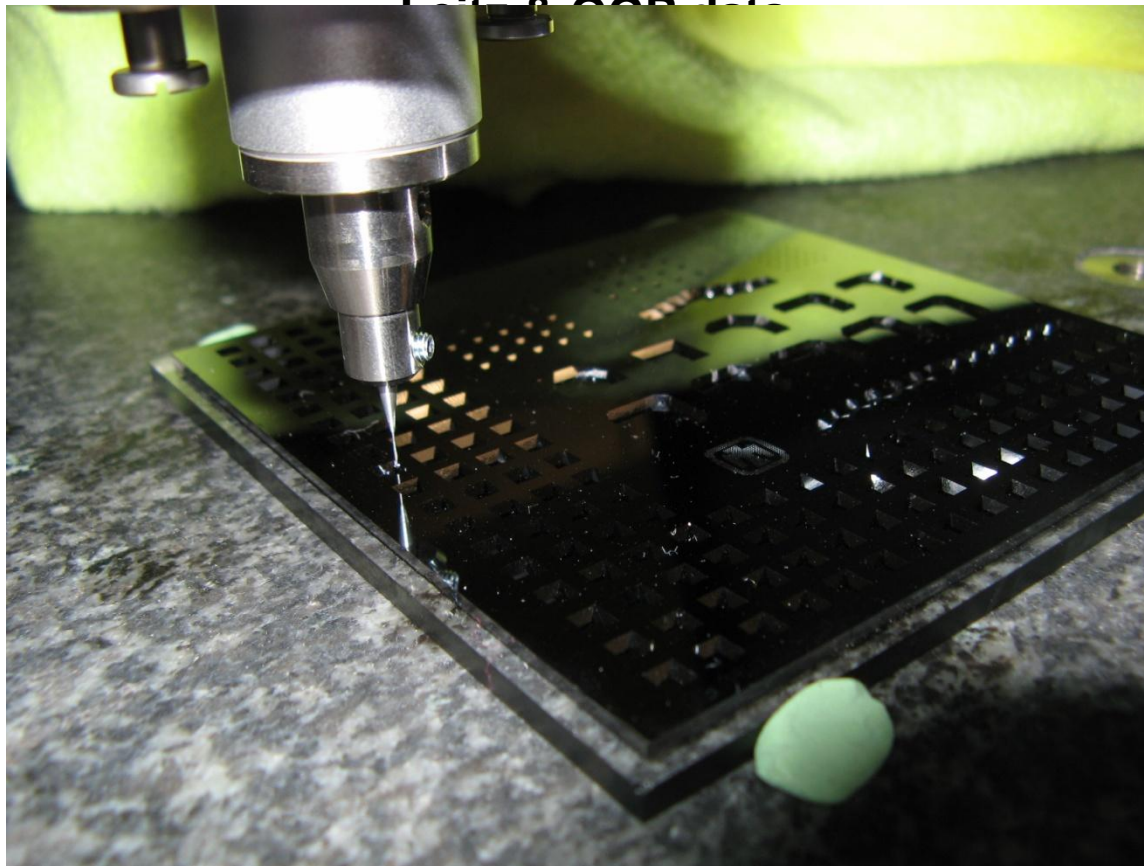


Estimates of measurement uncertainty

- **Mainly type B, based on:**
 - **Simulation of roughness**→ $0.4\ \mu\text{m}$
 - **MPE of equipment**→rectangular distribution
- **Repeatability of measurements significantly smaller than type B evaluation**
- **We estimate: Larger of either $0.4\ \mu\text{m}$ or MPE converted from rectangular to normal at $k=2$**

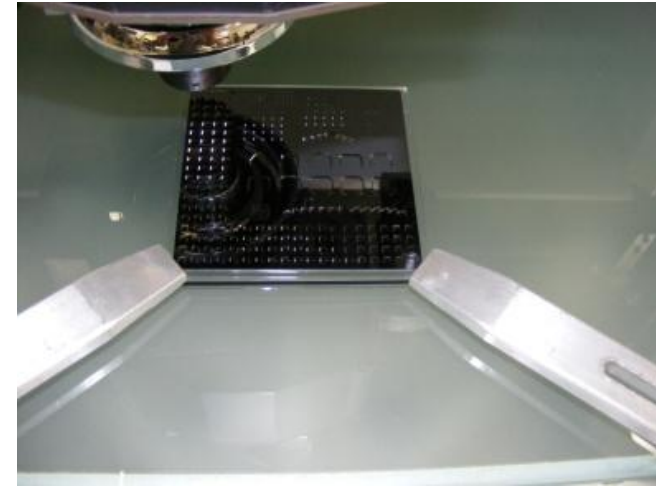
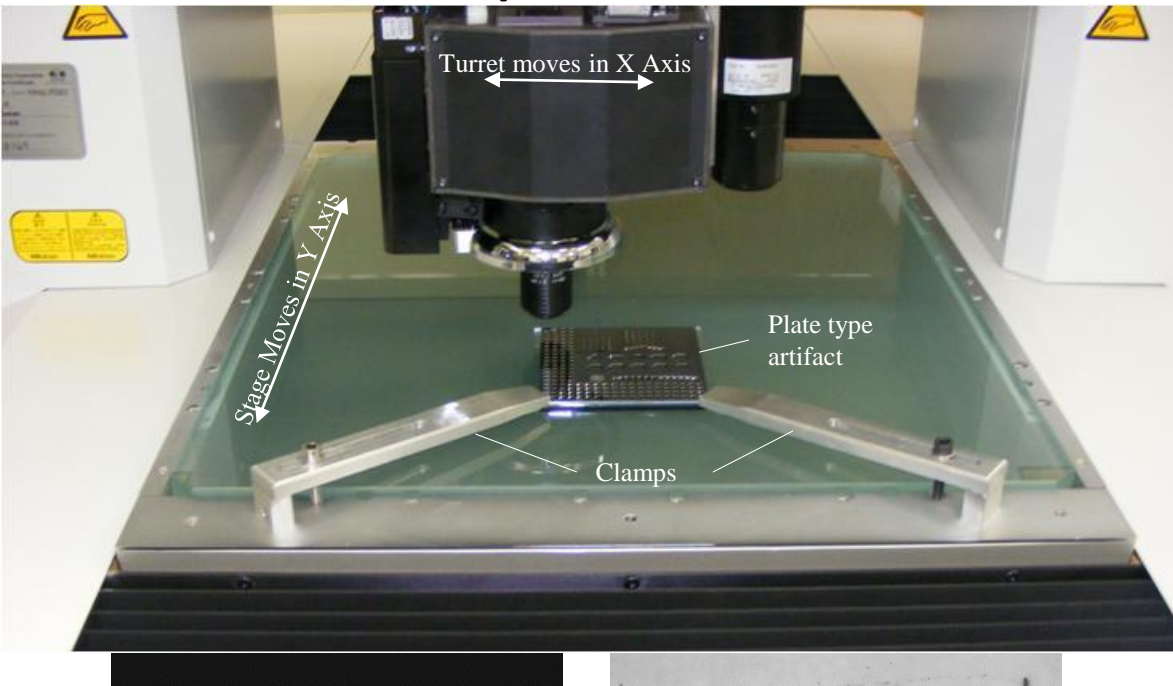
Leitz & OGP measurement results

Measured Size - Design Size (μm)



MEI measured the plate type artifact with QV Ultra

Measurement setup on QV Ultra



Artifact clamped to stage

- 25 X objective, calibrated before measurements
- QV box tool used. Both rising edge and falling edge algorithm were tested
- QV Ultra machine was recently calibrated
- The artifact was attached to the QV stage in three different ways: Clamp, clay, resting (just placed on stage)

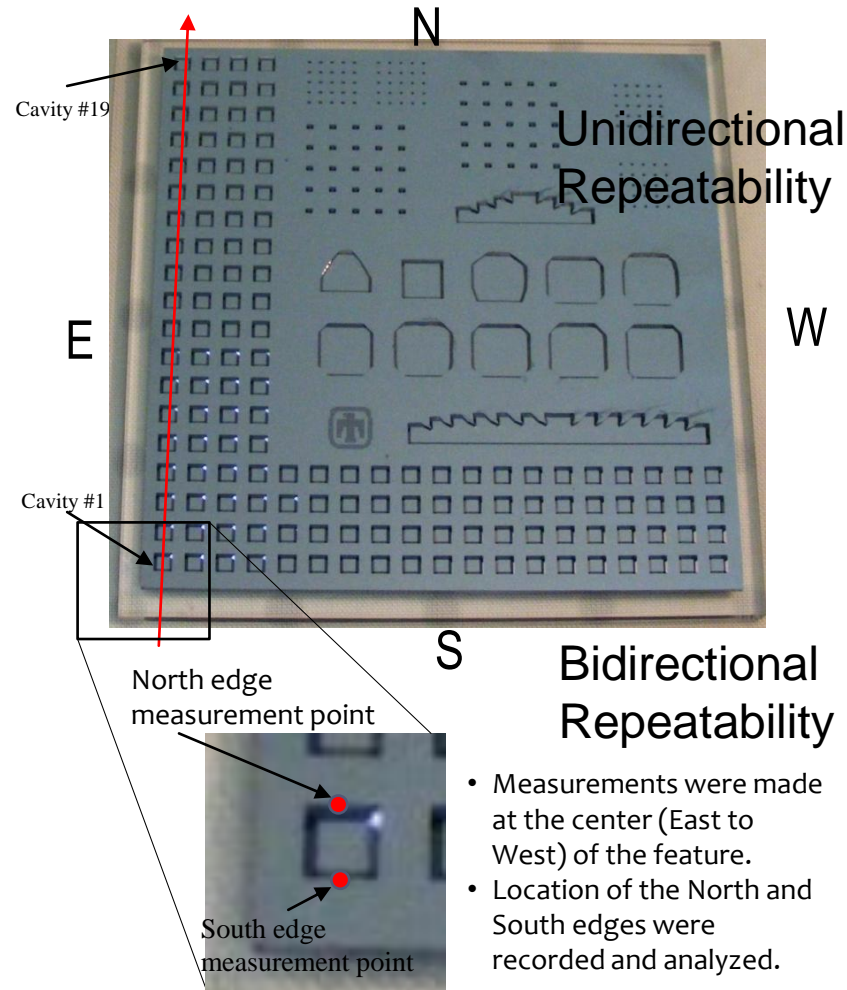


Artifact held with clay

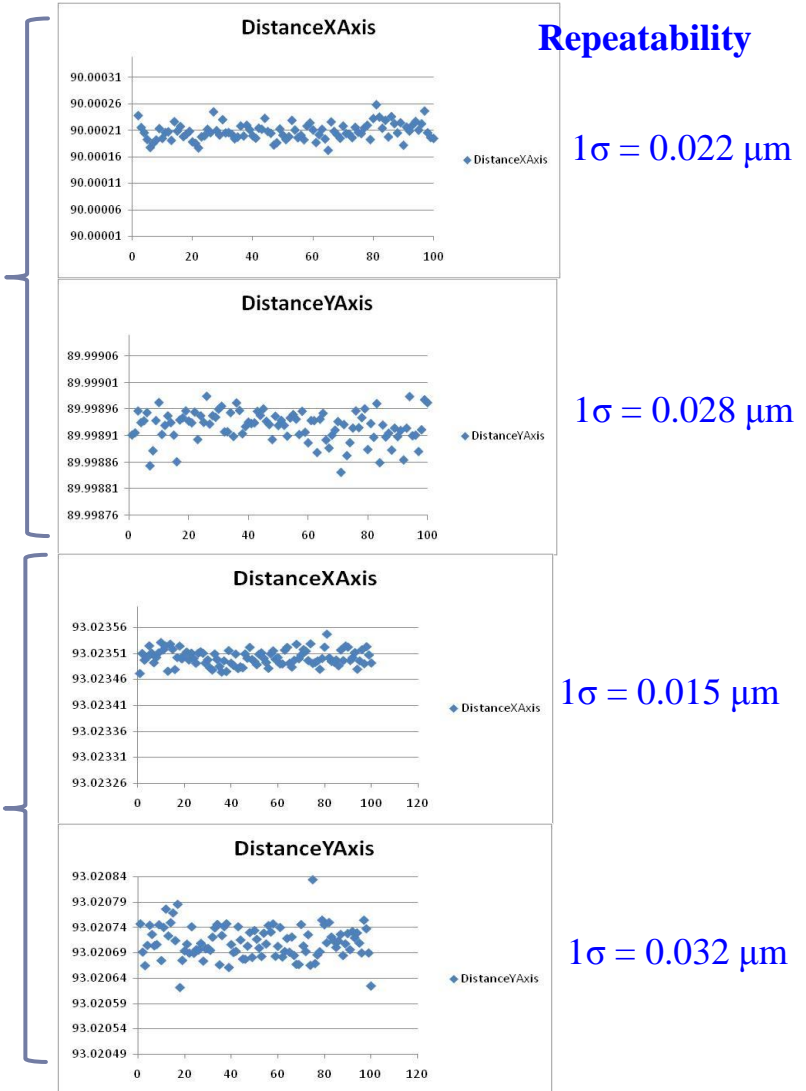
QV Ultra measurements at Micro Encoder Inc

- Measurements were made using MEI's QV Ultra system (recently calibrated). Two sets of QV measurements were made using different measurement algorithms (rising edge and falling edge) with a 25 X objective.
- MEI measurements were made at the same nominal locations as Sandia measurements.

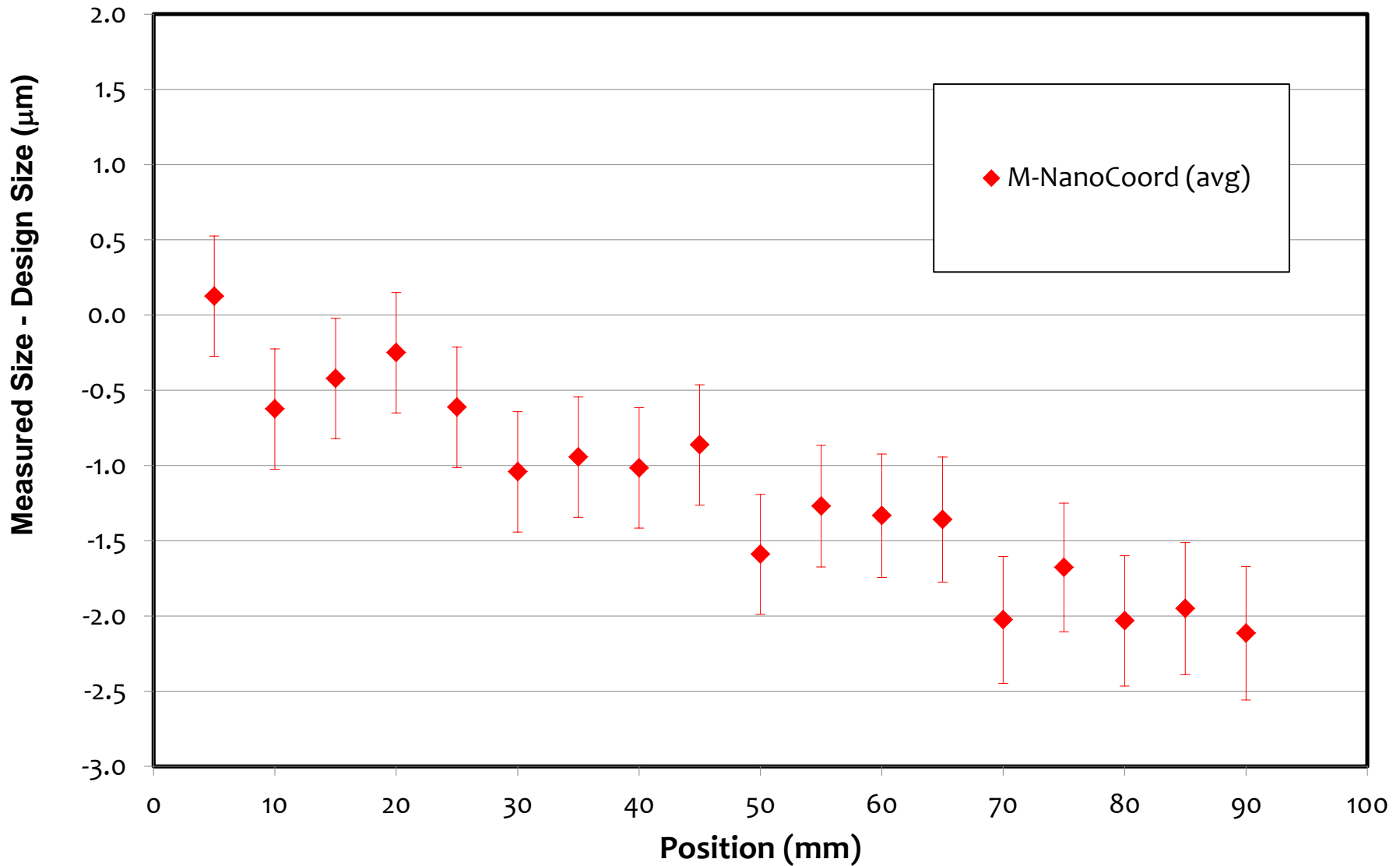
Measurements were made at the each cavity (1 ~ 19) along of the East most column, in the direction indicated.



- Measurements were made at the center (East to West) of the feature.
- Location of the North and South edges were recorded and analyzed.

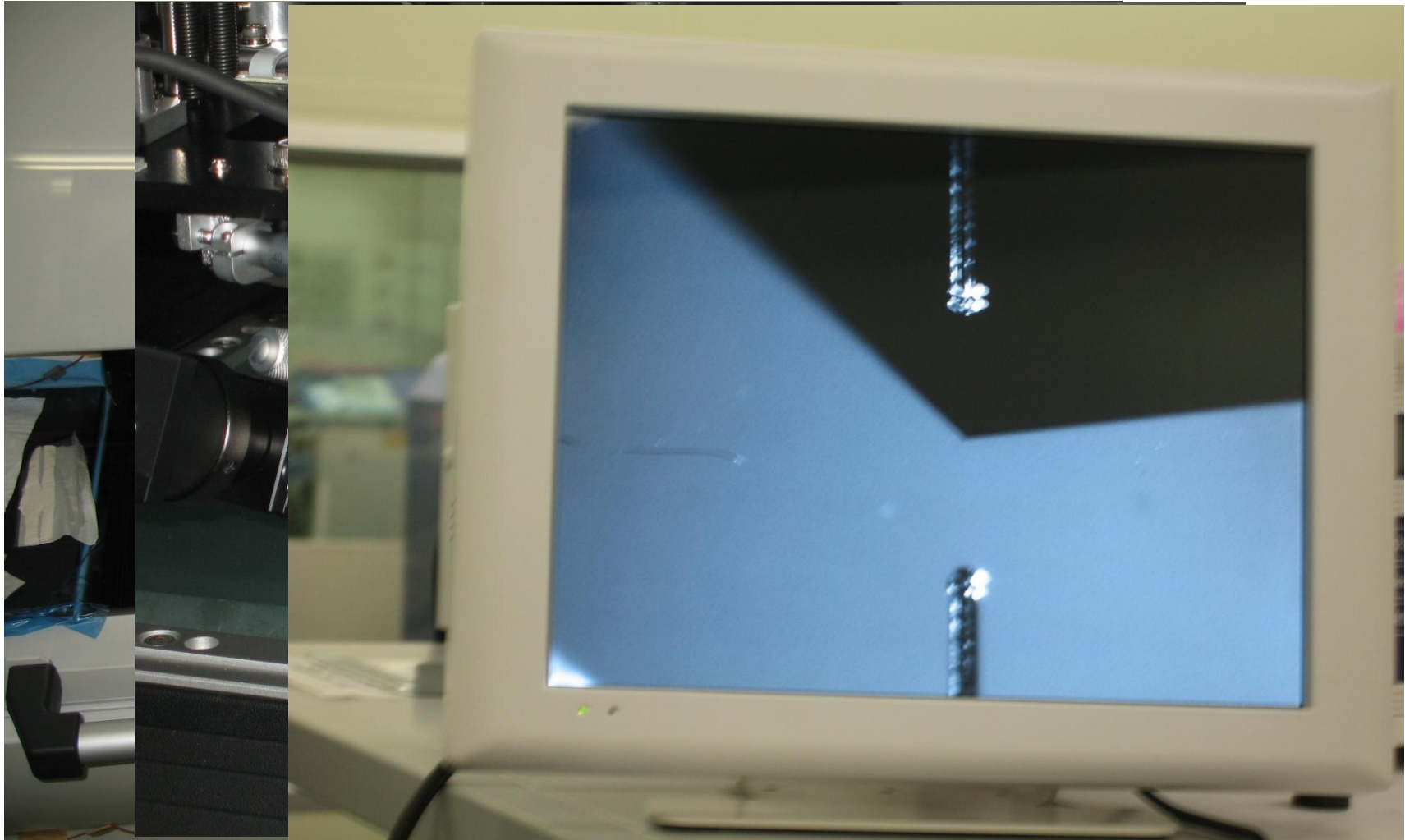


M-NanoCoord Results

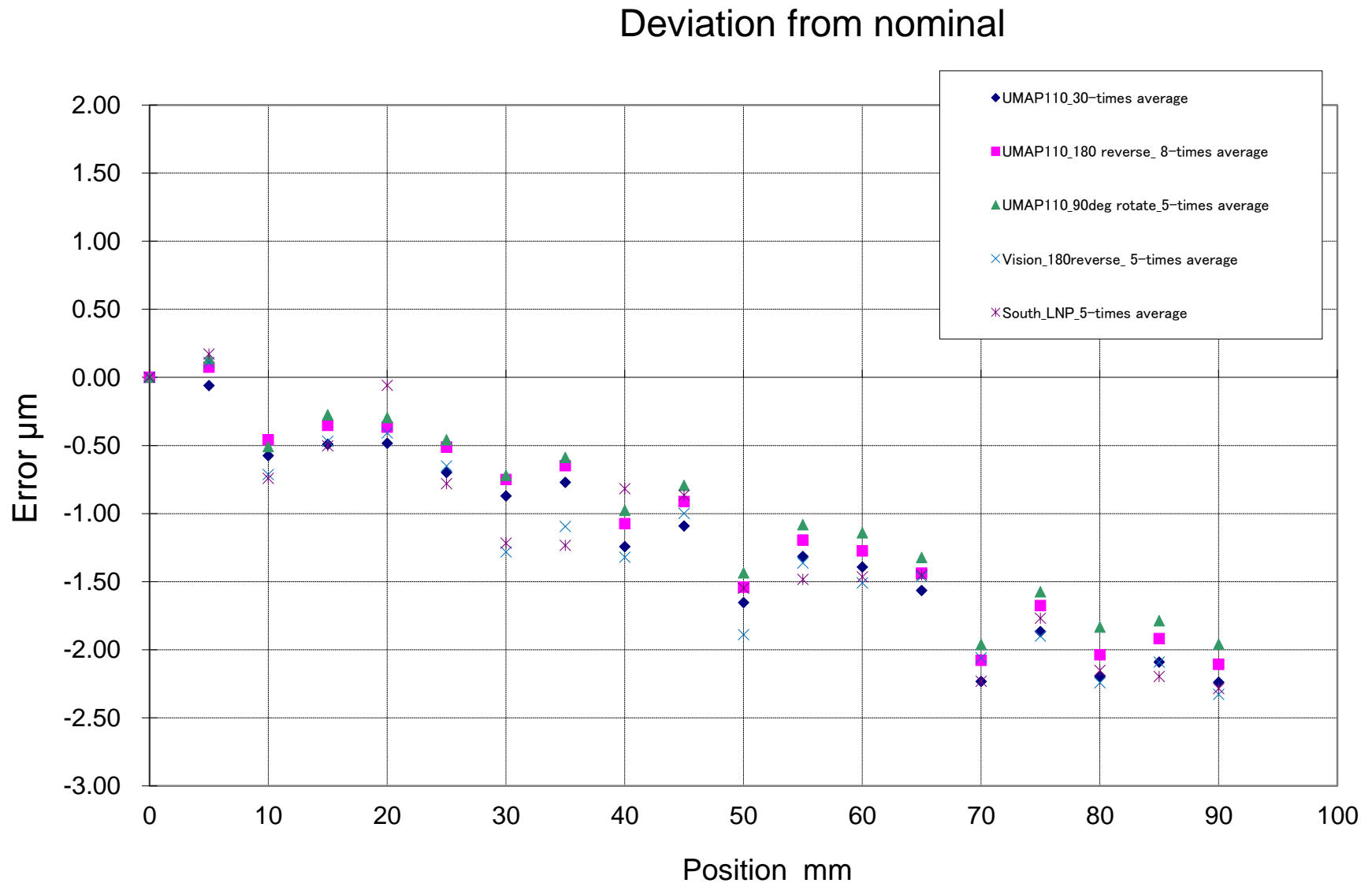


Mitutoyo M-Nanocoord measurements

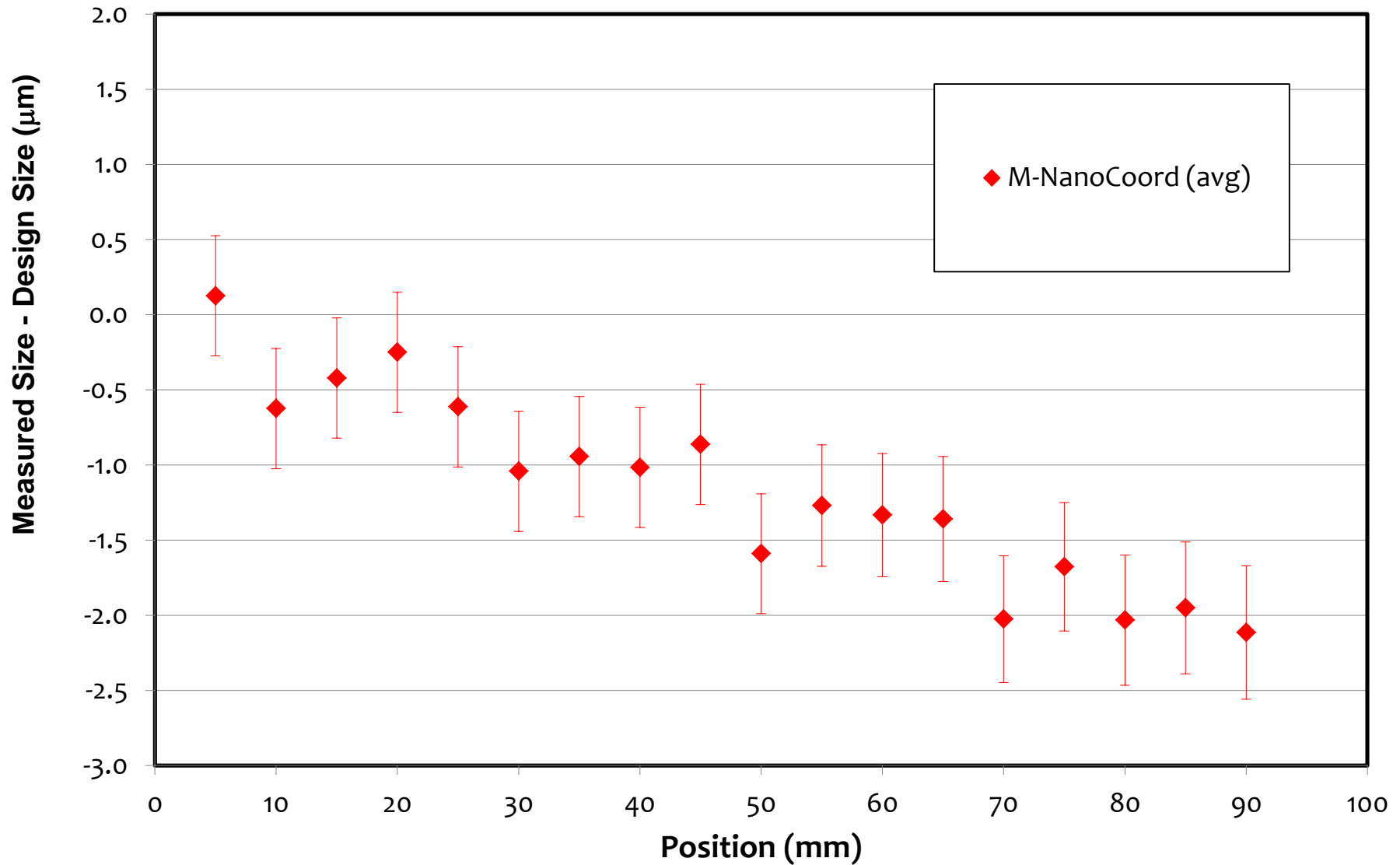
- Two different M-Nanocoords used
 - One uses both UMAP ultrasonic touch probe and optical vision probe
 - Other uses long-range ultralow force scanning probe (LNP probe)



M-Nanocoord intercomparison of probe systems

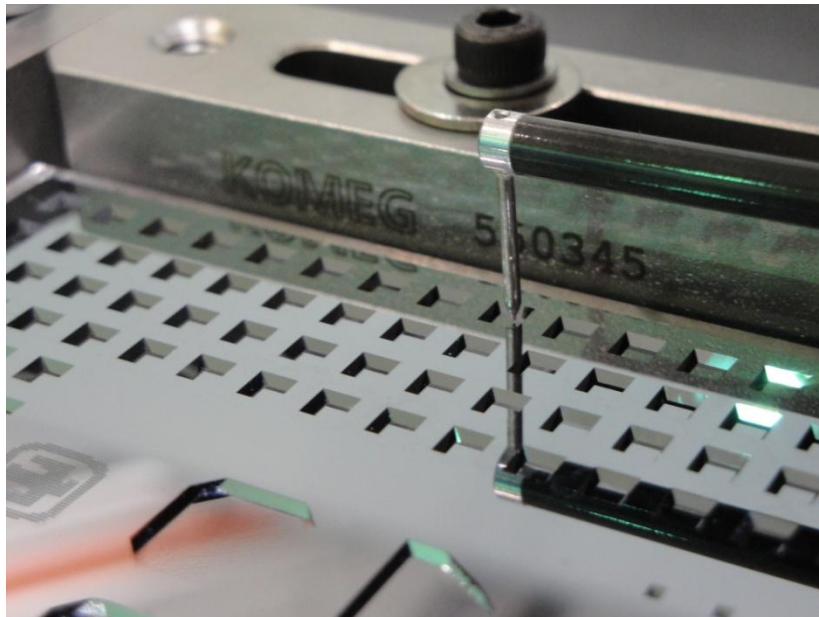


M-NanoCoord Results



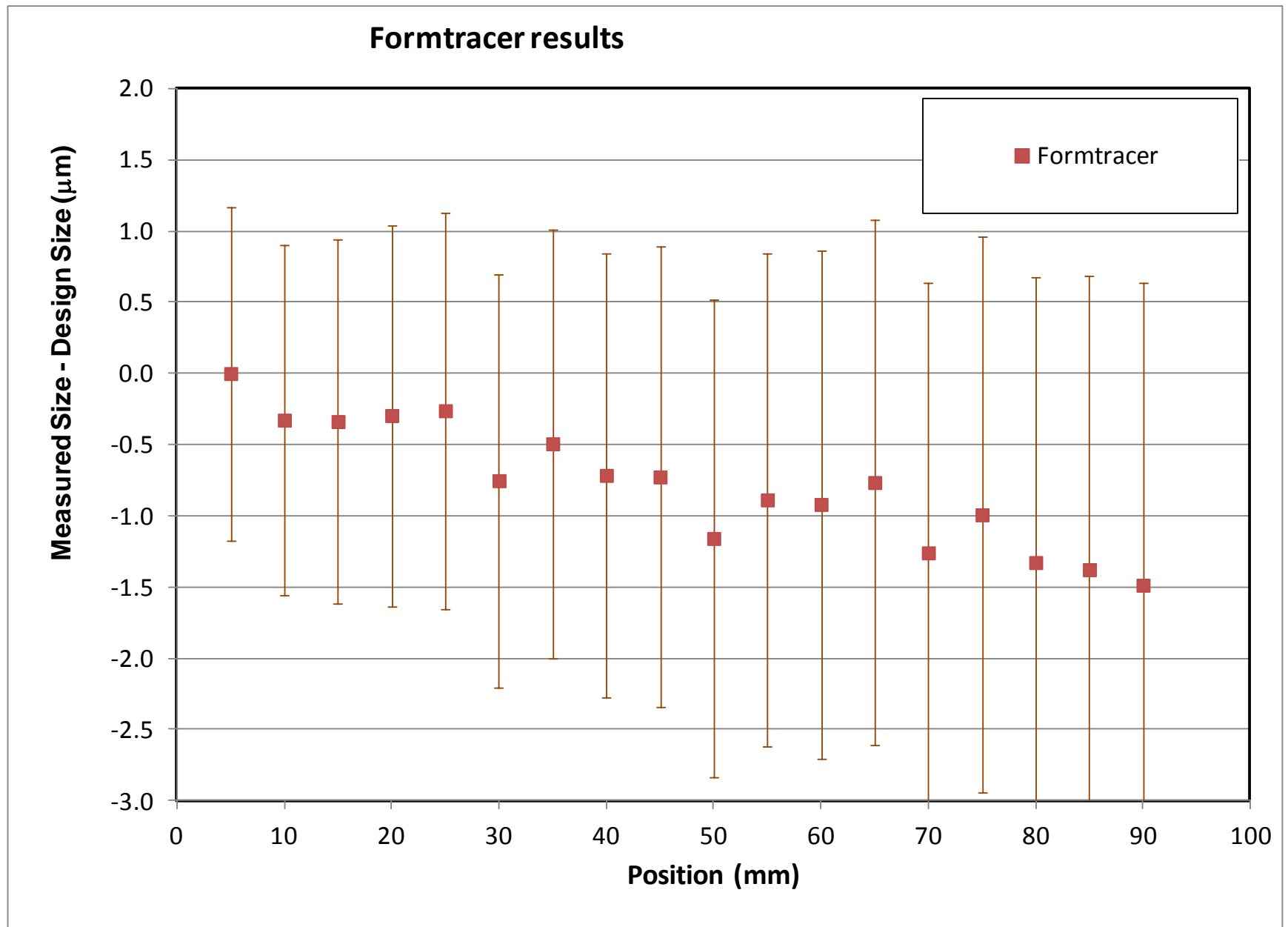
Setup

- A precision leveling table was used
 - Levelled to $\frac{1}{2}$ micron manually
- Two brackets were mounted to the precision leveling table in an “L” shape to manually align the artifact into a fixed position
 - Further alignment would be done via software

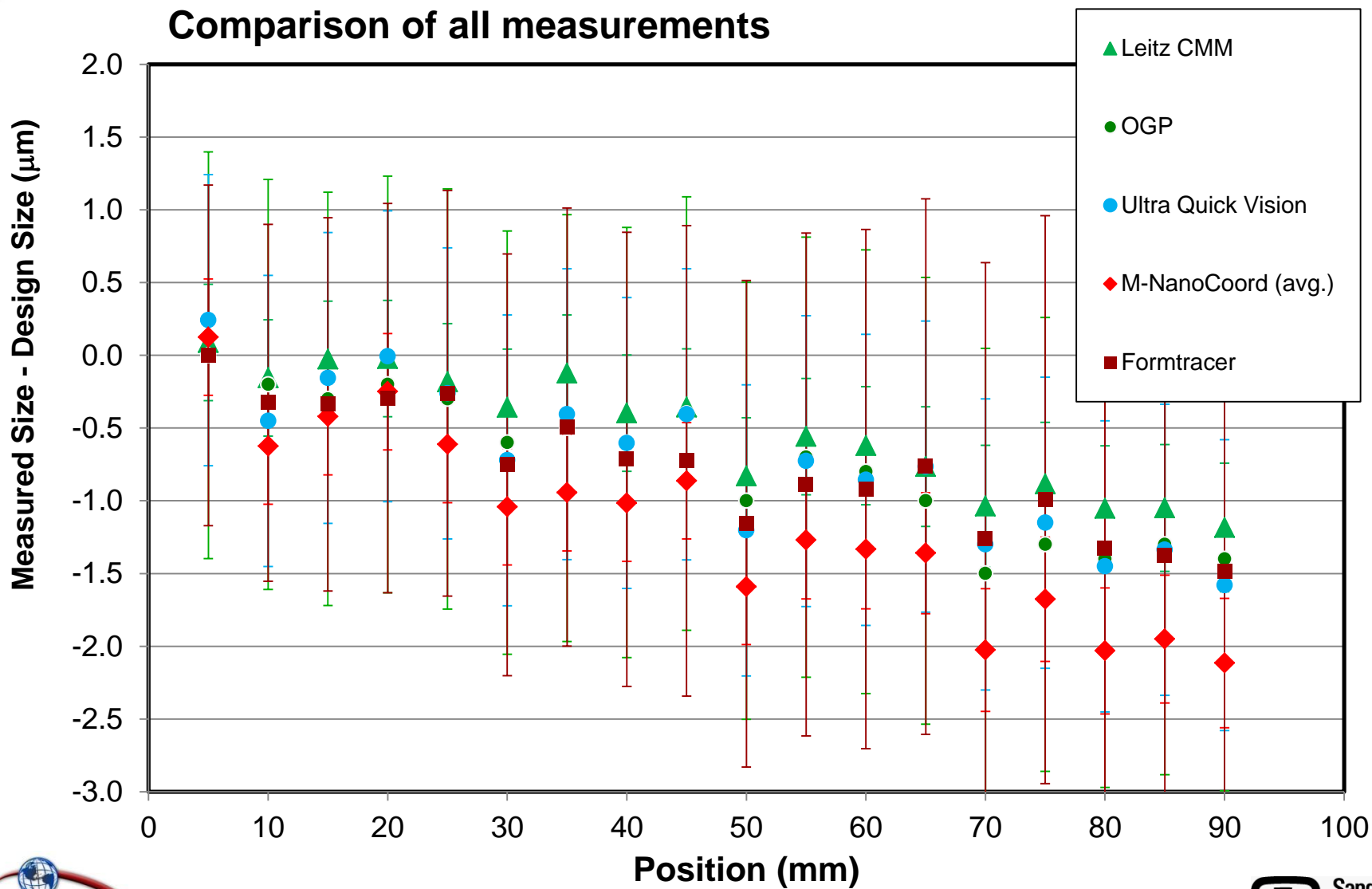


- Stylus used:
 - Number: 12AAD560
 - Stylus Tip Radius: $2\mu\text{m}$
 - Stylus Tip Angle: 60°
 - Stylus Tip Material: Diamond
- Stylus Measuring Speed: 0.1 mm/sec
- Measurement Force of Stylus: 0.75 mN

Formtracer CS-3100 measurements



Intercomparison of all results





Discussion & Conclusions

- **Manufacturing process still needs improvement**
- **Monte Carlo simulations show that even with rough sidewalls, expected measurement uncertainty of silicon artifact still $> 2x$ better than for chrome-on-glass grid plates**
- **Common mechanical edge/optical edge verified with M-Nanocoord measurements**
- **Light level change has little effect on pitch measurement (very good contrast and sharp lines)**

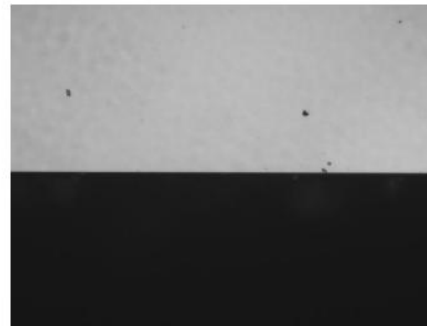
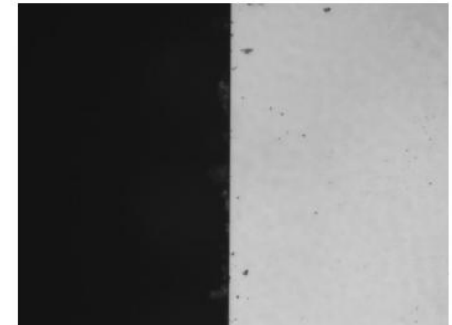
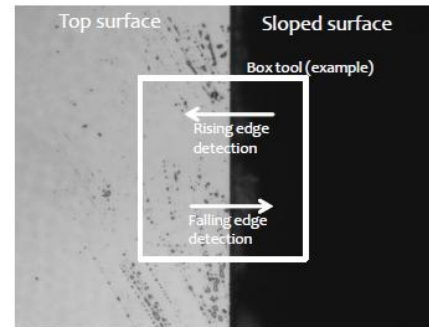
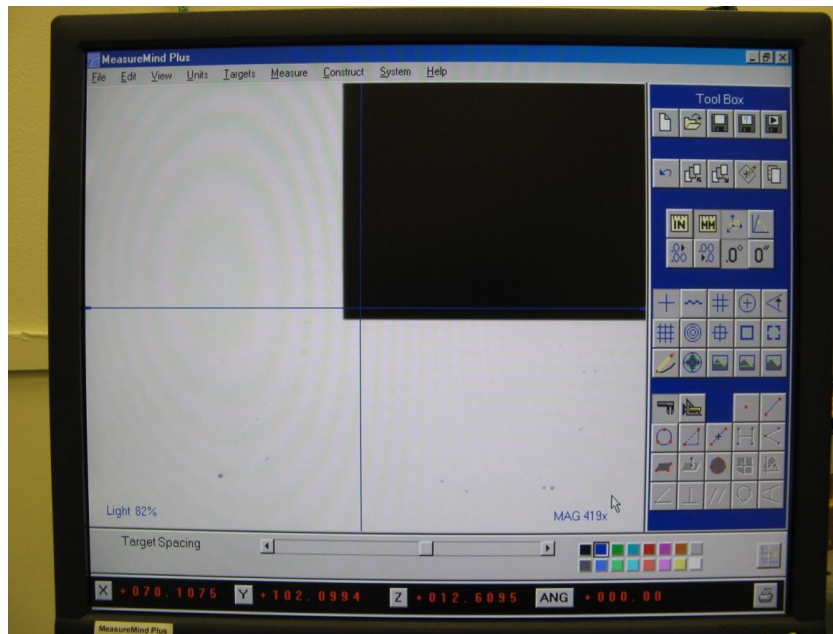


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- **Thanks for many technical contributions from: Todd Bauer, Margie Baca, Tony Bryce, Roger Burton, Andre Claudet, Ted Doiron, Orlando Espinosa, Harlan Gant, David Luck, Andy Oliver, Meghan Shilling, John Stoup, among others.**

Backup slides

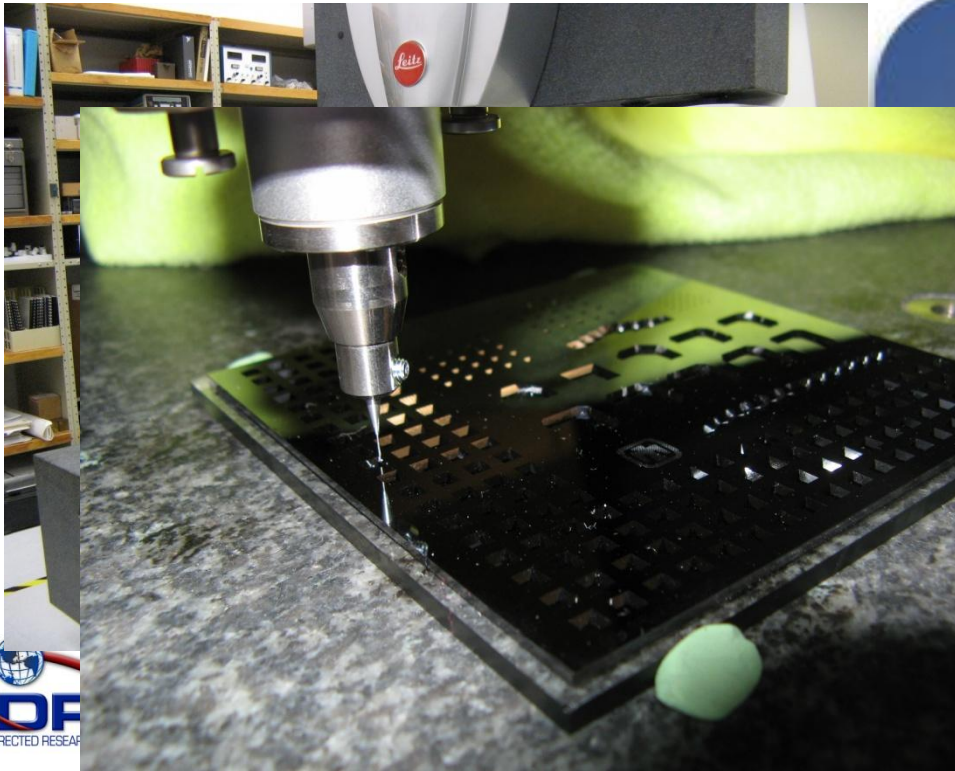
Effects of Roughness on Vision System



- Edges are very well defined with very good contrast, in spite of roughness on sidewalls

Initial CMM & optical CMM measurements

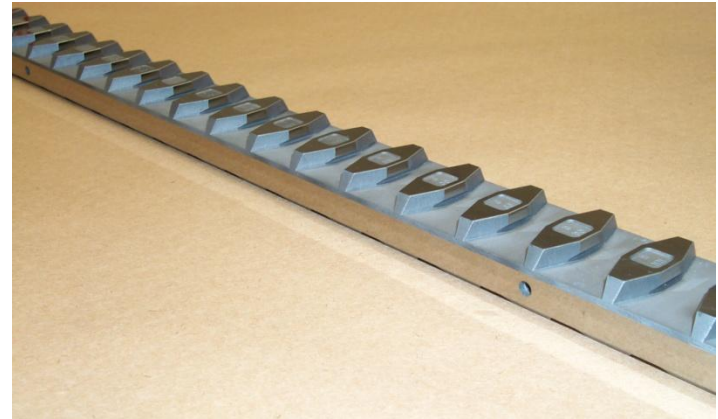
- CMM is Leitz PMM-C-Infinity 12.10.6
- $MPE_e = (0.3 + L/1000) \mu m$
- OGP Smartscope APEX
- XY Accuracy
 $(1.2 + 2L/1000) \mu m$



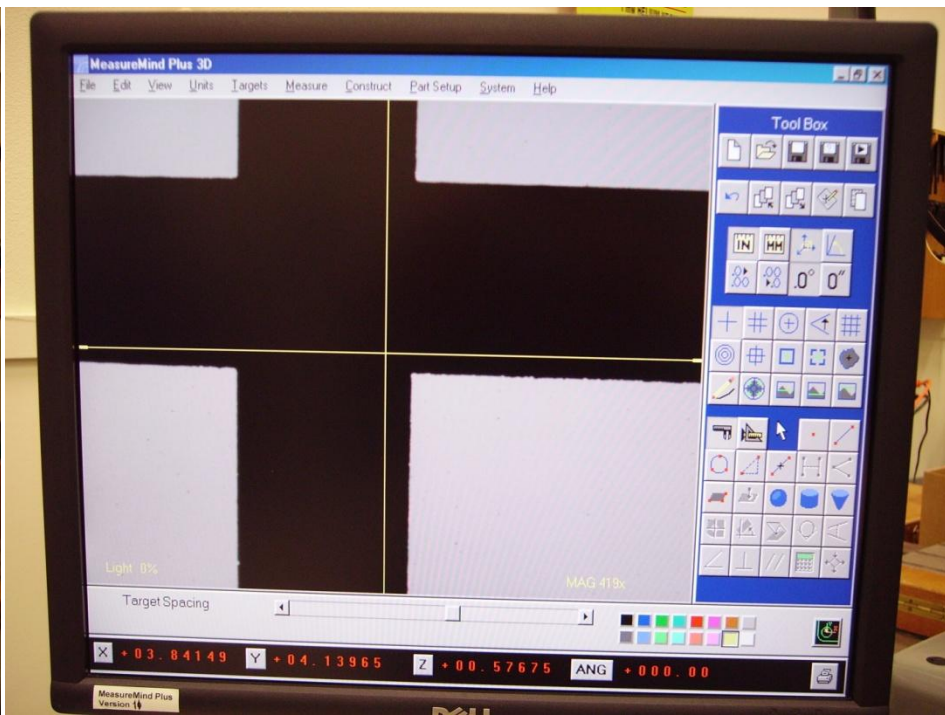
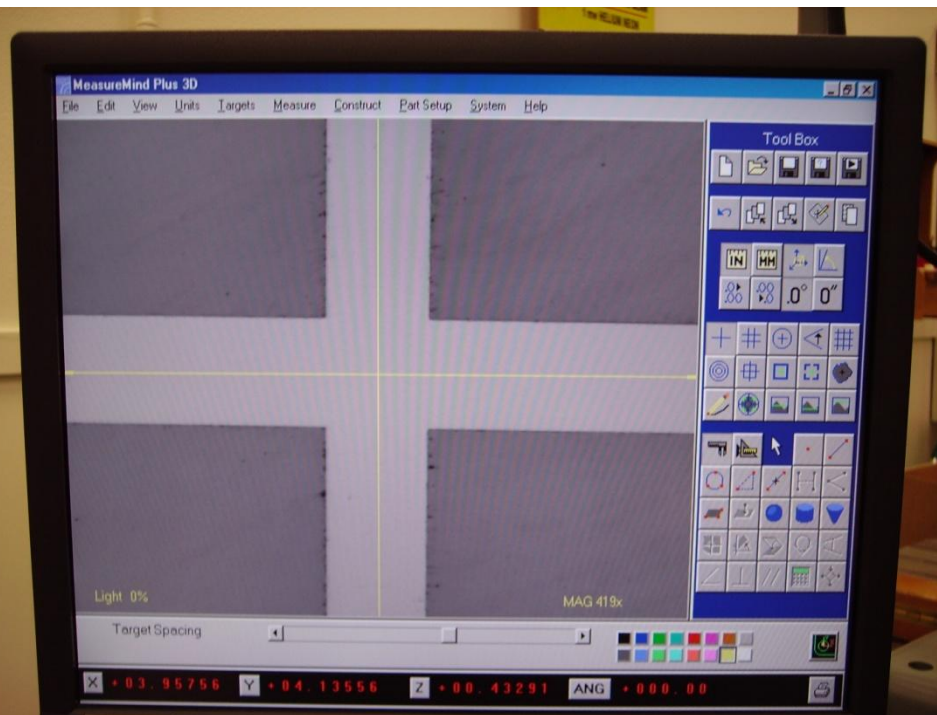


Design Ideas for Calibration Artifact

- Fabricate artifact which contains miniature versions of “macro” metrology
- Step gage
 - 1D performance evaluation, 2/3D with repositioning
- Ball plate
 - 2D performance evaluation, 3D with repositioning
- Other objects for investigation



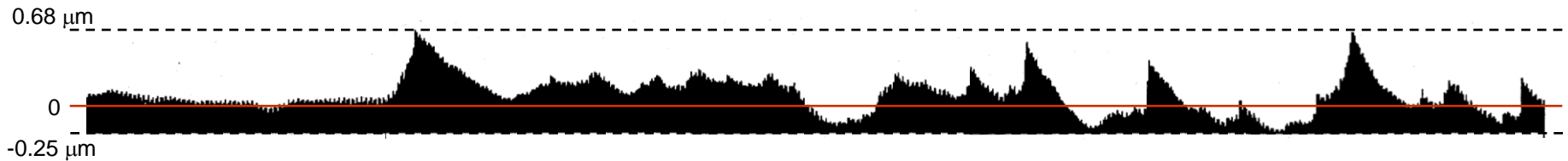
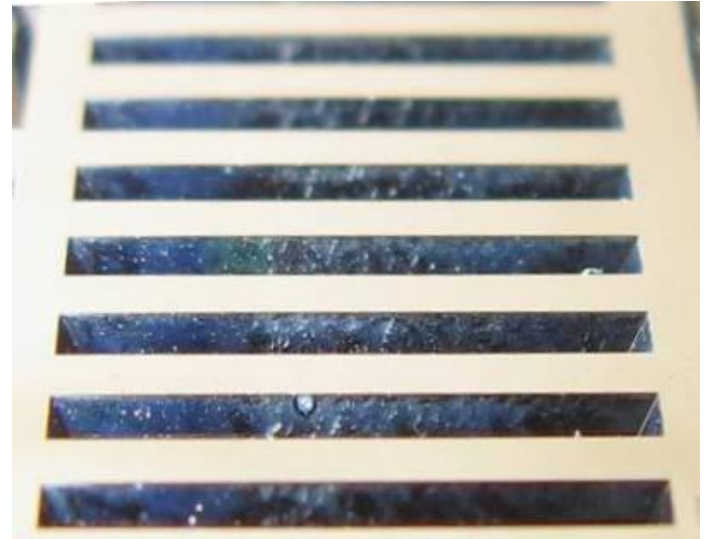
Typical grid plates





Manufacturing Issues

- Sidewalls are not smooth
- Appears that multiple crystal planes are being etched (misalignment?)
- Sidewalls may also be attacked by nitride removal process
- Effects of alternative removal processes studied



Edge Measurement with UMAP

- Mitutoyo UMAP Ultra
- Contact measurements with probe
 - 30 μm diameter
 - 2 mm stylus length
- Accuracy
$$(1.2 + 3L/1000) \mu\text{m}$$
- Repeatability
$$s < 0.1 \mu\text{m}$$



UMAP Edge Measurement

